M in im um aberration $2^{k p}$ designs of resolution III

Jesus Juan Lab. de Estadistica (E.T.S.I. Industriales) Univ.Politecnica de Madrid, Spain E-mail: jjuan@etsii.upm.es J.G abriel Palom o Dep.Matematica Aplicada A.T. Univ.Politecnica de Madrid, Spain E-mail: palomo.san@euatm.upm.es

ABSTRACT

In this article we prove several important properties of 2^{k} ^p m in im um aberration (M A) designs with k n=2, where n = 2^{k} ^p is the number of runs. We develop a simple method to build M A designs of resolution III. Furthermore, we introduce a simple relationship, based on product of polynom ials, for computing their word-length patterns.

K eywords: de ning relation, fractional factorials, orthogonal arrays, sm all run designs, word-length pattern.

AM S classi cations: Prim ary 62K 15; secondary 62K 05.

1 Introduction

 2^{k} ^p designs are commonly used in experimentation, where k is the number of factors and $n = 2^{k}$ ^p is the number of runs or observations. These designs are economical, statistically e cient and simple to analyze (see Box and Hunter, 1961).

In many applications, especially in industrial experiments, it is often necessary to determ ine which factors among a large number of candidates could a ect a particular response. For a given number of factors k, a usual procedure is to select a rst fractional 2^{k-p} design to accommodate the factors with the smallest number of runs. Confusion of e ects may lead to more than one plausible explanation of data. The initial design should be chosen in such a way that simpli es as much as possible the analysis stage and reduces the size of subsequent experim entation; see Box, Hunter and Hunter (1978) or Tiao (2000) for exam ples. W hen the experim enter has litthe know ledge about the relative sizes of the factorial e ects, the m in im um aberration (MA) criterion selects designs with good overall properties. A detailed discussion on the MA criterion can be found in Fries and Hunter (1980) and Chen, Sun and Wu (1993). Since Fries and Hunter (1980) introduced this criterion, m any articles have been devoted to nd M A designs and to study their characterization and structure, for example, Franklin (1984), Chen and W u (1991), Chen (1992) and Tang and W u (1996).

In addition to their direct practical application, m inim um aberration designs are also useful in the construction of more complex designs. For exam – ple, Ankenm an (1999) includes four-level factors in a design, and B ingham and Sitter (1999) and H uang, Chen and Voelkel (1998) use them to obtain m inim um aberration two-level split-plot designs.

M A designs can be obtained with reduced com putationale ort, particularly when the num ber of runs is low (16, 32 or 64). In this paper we propose an original procedure to obtain M A designs of resolution III in a sim ple way. This result could be useful from a practical point of view when the num ber of runs is high. That is not, how ever, our main interest. Following the work of Tang and W u (1996), we wish to understand the structure of M A designs, establishing som e of their characteristic properties, and to place them within the global structure of designs with a xed num ber of runs. W e will see graphically that this structure presents interesting properties.

In this paper we shall only consider screening designs. Thus, we will consider 2^k ^p designs which allow us to study k factors with a minimum number of runs $n = 2^{k} p$; i.e., n=2k n 1: There are two reasons for this choice: rst, they are preferred when the number of factors to be analyzed, k, is large; this is precisely the case when the search for a good design is more complex. Second, using a sym metry property (Tang and W u , 1996) the properties of designs with k < n=2 can be deduced from those with k n=2. As a consequence, a complete characterization of designs having k n=2 provides a characterization for all designs with n runs. M oreover, all designs with k n=2, except for one, are of resolution III (for k = n=2); and their comparison would require precise criteria to be able to discrim inate among them .

Finally, and in addition to providing a characterization of MA designs for k = 2; we also provide a way to replace the tedious computation of the word-length pattern vector by the computation of an elementary product of polynom ials.

This paper is organized in four sections. Section 2 introduces the problem and the notation. In Section 3 the main result for this paper is presented, namely the necessary condition for any 2^{k-p} design with k = n=2 to be of minimum aberration. Sections 4 and 5 are concerned with the computation of the word-length pattern, and from the results in these sections we complete the conditions which characterize MA designs.

2 De nitions and motivation

A complete two-level factorial design with m factors $B_1; B_2; ...; B_m$ contains the $n = 2^m$ possible combinations of factor levels. U sually, -and + signs are en ployed to indicate the two levels of each factor and the design is presented in a design matrix, which has m columns, one per factor, and 2^{m} rows corresponding to the factor treatments. The m columns are independent in that none of them can be obtained as a product of the remaining ones. To sim plify the presentation, we shall call these columns or factors the basic ones. By multiplying these columns in all possible ways we can generate up to 1 additional ones, which will be identied by the combination $s = 2^m$ m (juxtaposition) of the basic factors which generate them $_{i}(B_{1};B_{2};...;B_{m})$ or more concisely as i. The individual elements of column i are obtained by multiplying the corresponding elements of the columns specied in $_{i}(B_{1};B_{2};...;B_{m})$: The collection of the 2^{m} 1 colum ns

H_m = fB₁;B₂;:::;B_m; 1; 2;:::; sg

is the key set through which any 2^{k-p} designs with 2^{m} runs can be de ned. In coding theory the set H_m is known as a Hamming code. For example, if we use A;B;C;D for the four initial columns of the complete 2^{4} design, we obtain

H₄ = fA;B;C;D;AB;AC;AD;BC;BD;CD;ABC;ABD;ACD;BCD;ABCDq:

Multiplying any colum n of H_m by itself we obtain the I colum n, where all signs are +. The set fIg[H_m with the de ned operation has a structure of an abelian group, where I is the nullelem ent. The result of the product of sign colum ns can also be derived by looking at the products of the com binations of letters which represent them. For example, the product of colum ns ABC and ABD produces the colum n CD; since AA = I, BB = I:

De nition 1 A subset d of k columns of H $_m$ represents a 2^k p design.

For example, the following subset of 9 columns of H $_4$

$$d_1 = fA; B; C; D; ABC; ABD; ACD; BCD; ABCDg$$
 (1)

is a 2^{9} ⁵ design:

The advantage of this de nition derives from its generality; it enables us to de ne any design with $n = 2^m$ runs, whether it is a complete factorial design or a fractional design $2^k p (k > m)$. Moreover, through this de nition

we can make use the tools of set theory. We will then say that a given design contains another, is the union of two others, and so forth.

Many subsets form ed by dierent elements of H m provide equivalent designs which for our work will be considered the same. Two designs are equivalent if it is possible to de ne an isom orphism between them (see for example, Tang and W u, 1996). Thus, Pu (1989) proved that there are only ve di erent 2^{9} ⁵ designs, so that any subset of H ₄ with nine elements is equivalent or isom orphic to one of those designs. If we consider all designs, with any number of factors, the number of dierent designs with n = 16runs is reduced to 45 (46 if we include?). In gure 1 we present a graph showing the relationship between them . Each point or node in the graph is a design. The starting point is the empty set? (k = 0); for k = 1 all designs are equivalent and are represented by a single node, and the sam e occurs for k = 2:For k = 3 there are two di erent designs, fA ;B ;C g and fA ;B ;AB g; for k = 4 there are three, and so forth up to k = 15 which is the H₄ design. The lines connect pairs of designs which only dier in one element, which in some cases (solid lines) is indicated on the arc. The design with k + 1columns is obtained by adding the column which appears on the arc that connects it to its predecessor. The designs for k > 8 can be obtained by symmetry, starting from H_4 and eliminating the columns specied in the sym m etric arcs.

One of the most important properties of this graph is its symmetry, due to the fact that if two designs d_1 and d_2 are equivalent, so are their complementaries d_1 and d_2 . The notation d will be used to represent the complementary of a given design d, where $d = H_m$ nd. Thus, within the subsets of H₄, there are four di erent designs for k = 5, there exist four others for k = 10, which correspond to the complementaries of the rst ones. In gure 1 the complementary of a design with k columns is the symmetric with 15 k columns. The relationships between complementary designs are analyzed by Tang and W u (1996). In accordance with this, the properties of one half of these designs (k < n=2) can be deduced from the other half k n=2. In this paper we shall concentrate in the analysis of M A designs for k n=2

The goodness of a design is a consequence of the relations of dependence between its columns. Let us consider the design d H_m ; with columns d = f₁; ₂; ...; _kg: A word of length i consists of i elements _{j1}; _{j2}; ...; _{ji} from d such that

$$j_{1} j_{2} \qquad j_{i} = I \tag{2}$$

where I denotes the column having all + 's. The set of all distinct words

form ed by products involving elements of d gives the de ning relation of the design. The words in the de ning relation correspond to all the interactions of the k factors that are confounded with the mean (represented by colum n I). The vector

$$W$$
 (d) = [a₁ (d); a₂ (d); :::; a_k (d)]

is called the word-length pattern (W LP) of the design d, where $a_i(d)$ is the number of words of length i. W e shall use in the future a_i instead of $a_i(d)$ whenever this does not lead to confusion.

The resolution of a design is the length of its shortest word. Maximum resolution is the usual criterion to select a design. However, for given k and p, and specially when these values are large, there may exist many di erent maximum resolution 2^{k-p} designs. For instance, the ve di erent 2^{9-5} designs are of resolution III. Additionally, for k n=2 all H_m designs but one (the exception corresponds to k = n=2 and has resolution IV) are of resolution III.

Fries and Hunter (1980) introduced the notion of aberration as a more powerfulm ethod to compare fractional factorial designs. For two 2^{k-p} designs d_1 and d_2 ; suppose r is the smallest value such that $a_r(d_1) \notin a_r(d_2)$. We say that d_1 has smaller aberration than d_2 if $a_r(d_1) < a_r(d_2)$: The design d is of m inimum aberration (MA) if there is no other design with the same num ber of factors and runs having less aberration than d:

This previous analysis is of practical interest for designs with k > m; which are called fractions. The usual way of de ning a fraction is the following: rst m initial factors $b = fB_1; B_2; \dots; B_m$ g are taken to form the 2^m design, and then p additional factors $B_{m+1}; B_{m+2}; \dots; B_{m+p}$ are assigned to a subset ${}^0_1; {}^0_2; \dots; {}^0_p$; selected from $b = H_m$ nb: The selection is denoted by

$$B_{m+1} = {}^{0}_{1} (B_{1}; B_{2}; ...; B_{m}) \approx B_{m+2} = {}^{0}_{2} (B_{1}; B_{2}; ...; B_{m}) \approx B_{m+2} = {}^{0}_{2} (B_{1}; B_{2}; ...; B_{m}) \approx B_{m+p} = {}^{0}_{p} (B_{1}; B_{2}; ...; B_{m}) \qquad (3)$$

The design d is thus

$$d = B_1; B_2; ...; B_m; \frac{0}{1}; \frac{0}{2}; ...; \frac{0}{p}$$
(4)

This de nition requires the inclusion of the m basic columns. Any set of H_m containing m independent columns provides designs equivalent to those de ned from the above criterion. If we assume that this method has been applied to de ne the 2^k ^p design, the fraction is uniquely determined for

 ${}^{0}_{1}$; ${}^{0}_{2}$; ...; ${}^{0}_{p}$. Multiplying each relation $B_{m+j} = {}^{0}_{j}$ by B_{m+j} we obtain $I = {}^{0}_{i}B_{m+j}$. The p terms ${}^{0}_{i}B_{m+j}$ are called generators of the fraction and represent e ects confounded with the mean. These relationships are usually rewritten as

$$I = {}_{1}^{0}B_{m+1} = {}_{2}^{0}B_{m+2} = {}_{\overline{p}}^{0}B_{m+p} :$$
(5)

The product of two generators of (5) provides another e ect that is also confounded with the mean. The set of distinct words form ed by all possible products involving the p generators gives the dening relation of the fraction. It is usual to refer to letters instead of factors or columns. A letter is any of the labels B_i used to denote a factor. In this setting, as before, the product of two identical letters is the identity. The word length is simply the number of letters of a word.

For instance, if we call E; F; G; H and J the ve additional factors, the generators of the design (1) are

$$I = ABC \underline{E} = ABD \underline{F} = ACD \underline{G} = BCD \underline{H} = ABCD \underline{J}:$$
 (6)

(The non basic factors have been underlined). By taking all possible products in which the vegenerators of (6) are present, we obtain the 32 words (31 if we exclude I) which form the de ning relation of the fraction. From the lengths of the words we obtain the following W LP,

The resolution of this design is III, which is the maximum for 2^{9-5} designs.

For the cases to be considered, k = n=2, any subset has always m independent columns and always leads to designs which can be dened by means of the scheme described in (3). In the following sections we shall use any of the two forms of identifying a design.

The W LP is an essential instrum ent to evaluate a 2^{k} ^p design and its computation requires p independent generators. In section 5 we shall encounter designs which are de ned for subsets of H m that do not include the basic columns such as

$$d_2 = fA; BC; BD; CD; ABC; ABD; ACD; BCD; ABCDg:$$

A simple method to obtain the generators consists in transform ing d_2 by means of an isomorphism into another set with structure (4). For instance, the isomorphism T de ned by T (A) = A;T (B) = BCD;T (C) = ACD and T (D) = ABD transform $s d_2$ into the equivalent design

fA;B;C;D;AB;AC;AD;BC;ABCg:

U sing E ;F ;G and J as labels for the non basic factors, the generators are

$$I = ABE = ACF = ADG = BCH = ABCJ$$
:

The W LP of d_2 is (0;0;8;10;4;4;4;1;0). Since $a_3(d_1) = 4$ and $a_3(d_2) = 8;$ d_1 is preferred from the aberration point of view.

Tang and W u (1996) propose a new approach to characterize M A designs in terms of their complementary designs. Let $H_m = d [d; they argue that$ $when the elements in d are more \dependent", those in d should be less$ $\dependent" and thus may have less aberration. They developed a general$ theory to support this intuition. Here we give a di erent version of Tangand W u's intuition based in the concept of rank which we de ne as follows.

De nition 2 The rank of a set f of columns of H $_{\rm m}\,$ is the number of independent columns it contains.

The rank of H_m is m and hence the rank of any subset f H_m is never larger than m : M oreover, the maximum number of elements of a subset f with rank v is 2^{v} 1: Therefore, if the number of elements of a set is h, its m inimum rank is

$$v_h = dlog_2 (h + 1)e;$$

where d(a)e is the sm allest integer larger or equal to a:

The maximum resolution (and also the MA) fractions always have maximum rank equal to m. In the next section we shall also see that the com - plem entary design of a MA design has minimum rank.

Let us go back to gure 1 to identify the MA designs. For each value of k in the gure, we have identify the MA design. The complementary (symmetric) of a MA design is the worse design from the aberration point of view. All designs with k 8 are of resolution III with the exception of a design for k = 8 having resolution IV (the circled one). This design is called saturated design with resolution IV and plays an essential role when building minimum aberration designs. We can observe that all minimum aberration designs for k > 8 start from it. This property and other related ones are generalized in the following sections.

3 Screening designs (k n=2) of m in im um aberration

Let d be the 2^{k} ^p design with n=2 k n 1; de ned by the generators $I = {}^{0}_{1}B_{m+1} = {}^{0}_{2}B_{m+2} = {}^{0}_{\overline{p}}B_{m+p}$: Our goal is to choose ${}^{0}_{1}$; ${}^{0}_{2}$; ...; ${}^{0}_{p}$ in such a way that the design d is of m inim um aberration.

The solution for the case k = n=2 is well known. G iven the basic columns $B_1;B_2;\ldots;B_m$; it consists in assigning the (n=2 $\,$ m) non-basic factors to the columns obtained as the product of an odd number of basic ones. There is only one possible design of resolution IV and hence it is of minimum aberration.

Let $'_{1}$; $'_{2}$; ...; $'_{q}$ with $q = 2^{m-1}$ m; be all the odd combinations of the basic columns B_{1} ; B_{2} ; ...; B_{m} : The generators of the $2^{l q}_{IV}$ design with $l = 2^{m-1}$ are

$$I = {'}_{1}B_{m+1} = {'}_{2}B_{m+2} = = = {}_{q}B'_{m+q}$$
(8)

From now on we will denote this design as O_m :

The extrem e case is obtained when k = n = 1; and corresponds to the maximum number of factors which can be analyzed with a regular fraction of n runs. This design is called a saturated design of resolution III (or just a saturated design) and will be denoted as H_m ; since it contains all its columns.

W hen the number of factors to be studied is $n\!=\!2 < k < n - 1$; the maximum resolution of the design is III. The resolution criterion does not discrim inate among designs with this number of factors and it is necessary to use the aberration criterion to di erentiate between them . The following theorem gives a condition for a design with a number of factors $k > n\!=\!2$ to be of MA.

Theorem 1 Let d H_m be a 2^k ^p design and d its complementary, $H_m = d [d. A$ necessary condition for d to be of m in imum aberration is that the set d has m in imum rank.

The proof, based on a combinatorial argum ent, is given in appendix 1.

It should be noted that theorem 1 does not lim it the num berh of colum ns of d. W hen h > n=2, the rank of the set d of colum ns to be elim inated is always m and the theorem is trivial. The result is important for h < n=2, which corresponds to designs of resolution III. W e wish to emphasize the interest of this result when looking for M A fractions. For example, the 2^{12} ⁸ design with generators

$$I = ABC\underline{E} = ABD\underline{F} = ACD\underline{G} = BCD\underline{H} = AD\underline{J} = BD\underline{K} = CD\underline{L} = ABCD\underline{M};$$
(9)

is obtained by elim inating from H_4 the columnsd = fAB; AC; BCg; which form a set of rank 2. The W LP of (9) is

(0;0;16;39;48;48;48;39;16;0;0;1): (10)

If instead of elim inating the columns indicated above we choose fAB; AC; ABCDg; which has rank 3, the fraction obtained has as W LP

(0;0;17;38;44;52;54;33;12;4;1)

that has ${\tt m}$ ore words of length 3 and is therefore worse from an aberration point of view .

W hen the number of columns eliminated is $h = 2^v$ 1; where v is any integer, the choice of a set d with minimum rank ensures that the resulting fraction has minimum aberration. This is due to the fact that all sets of minimum rank and 2^v 1 elements are isomorphic, Tang and W u (1996).

W hen k > n=2, the number of generators needed to de ne a design is larger than the number of odd combinations of the basic factors. We will show that the minimum aberration design is obtained by adding r = k = n=2additional columns to O_m . In this case, q out of the p generators needed are the same as those used in the saturated design (8). Hence, we just have to nd the additional r = p q generators among the $2^m = 1$ 1 free columns of H_m , which correspond to the even products of the basic ones $B_1; B_2; \ldots; B_m$: We shall denote these columns as i, to distinguish them from the odd ones i; the set they form will be denoted as

$$E_{m} = {}_{1}; {}_{2}; ...; {}_{2^{m-1}} {}_{1} :$$
 (11)

 $E_m = H_m$ and fIg[E_m form s an abelian subgroup of fIg[H_m : The sets E_m and H_m 1 are isom orphic. The problem of choosing r columns from within the 2^{m-1} 1 even columns (E_m) is the same as the initial problem (choosing k from H_m), though from a set of lower dimension H_m 1. Therefore, the problem can be solved through a iterative procedure.

Theorem 2 Let $d H_m$ be a $2^{k p}$ design with n runs and k > n=2:A necessary condition for d to be of MA is O_m d:

Proof. Let $H_m = d$ [d; where the number of columns of d is $h = (2^m \quad 1)$ k: Since k > n=2; then $h < n=2 = 2^m \quad 1$ and, by theorem 1, the rank v of d should verify v m 1 for d to be of MA. The set E_m is isom orphic to any set with all its $2^m \quad 1$ 1 elements generated by m 1 independent columns. Let d^0 be the set isom orphic to d such that $d^0 \quad E_m$: The complementary of d^0 contains all the odd combinations of the basic columns and is isom orphic to d:

Another equivalent statement for the above theorem in terms of the dening relation is the following: any minimum aberration 2^{k} p design d

with $n = 2^{k-p}$ runs and k > n=2 can be de ned by

$$I = {}^{\prime}{}_{1}B_{m+1} = {}^{\prime}{}_{2}B_{m+2} = = = = {}^{m}{}_{q}B'_{m+q} =$$

= ${}^{0}{}_{1}B_{m+q+1} = {}^{0}{}_{2}B_{m+q+2} = {}^{m}{}_{r}B_{m+q+r}$ (12)

where ${}'_1;{}'_2;:::;{}'_q$ are all q = n=2 m columns obtained as odd products of three or more of the basic columns $B_1; B_2;:::; B_m$ and ${}^0_1; {}^0_2;:::; {}^0_r$ are even products of the basic set.

4 Saturated designs of resolution IV (O_m)

The strategy we presented in the next section to build resolution III designs takes $O_m = H_m$; the saturated designs 2^{1-q} of resolution IV with generators (8), as the starting point. For these designs $1 = 2^{m-1} = q + m$: The sm allest of these designs is 2^{4-1} , followed by 2^{8-4} , 2^{16-11} , 2^{32-26} and so forth.

The 2^{4} ¹ design de ned by the columns O₃ = fA;B;C;ABCg has the generating equation I = ABC<u>D</u> and W LP (0;0;0;1). The next design is O₄; a 2^{8} ⁴ fraction with generators

$$I = ABC \underline{E} = ABD \underline{F} = ACD \underline{G} = BCD \underline{H}$$
(13)

and W LP: (0;0;0;14;0;0;0;1):

The dening relation is one of the 2^m alias chains which appear in a design d H_m . The others correspond to the 2^m 1 columns or elements of H_m . Each chain includes 2^q confounded e ects. The set of these confusion chains is called the confusion structure. The confusion structure of O_m designs with generators given in (8), presents certain special properties of interest. The q generators of these fractions are even and therefore the 2^q words of the dening relation are even. The alias chains associated to a main e ect are obtained by multiplying the generating equation by the single letter associated to the factor; the result is a chain with 2^q odd e ects. Let $c_{2r+1;j}$ be the number of e ects of size 2r + 1 in the alias chains of B j, it can be seen that for all r,

$$c_{2r+1;1} = c_{2r+1;2} = \frac{1}{2r+q_{;1}} = \frac{1}{2r+1} = 1$$
 (14)

On the other hand, the $(l \ 1)$ columns of H_m not included in the set O_m are the product of an even number of basic columns $_{j} 2 E_{m}$. For the same reason as before, the alias chains associated to these columns are formed by

 2^{q} e ects which are even. If $b_{2r;j}$ is the number of e ects of size 2r in the alias chains corresponding to the even e ect _ _ 2 E _ ; then for any size 2r;

$$b_{2r;1} = b_{2r;2} = \overline{z_{r;2}}b_1$$
 (15)

These chains, which we shall call even chains, play a fundamental role in the computation of the word-length pattern for designs of resolution III with generators given in (12). Given a_{2r} , the value b_{2r} $b_{2r;j}$ is obtained through the following argument: the total number of e ects of size 2r which appear in the whole confusion structure of the fraction is $\frac{1}{2r}$; a_{2r} of which are words of the dening relation and the remaining e ects are distributed in the (1 1) even alias chains, i.e.

$$a_{2r} + (l \ 1)b_{2r} = \frac{l}{2r}$$
; $r = 1;2;...;l=2$ (16)

Since $l = 2^{m-1}$; the values a_{2r} and b_{2r} only depend on m and are easily obtained from the above expression and the following theorem.

Theorem 3 The word length pattern,

$$W = (a_1; a_2; :::; a_1);$$

of O_m ; the saturated design $2^{l q}$ of resolution IV, where $l = 2^{m l}$ and $q = 2^{m l}$ m, is obtained by m eans of the following recurrence laws:

$$a_{2r+1} = 0; r 0;$$

$$a_{2} = 0;$$

$$a_{2r+2} = \frac{1}{2r+2} \quad \frac{1}{2r+1} \quad (1 \quad 2r)a_{2r}; (r \quad 1):$$

Proof. The design generators are even words and the product of any subset of them is an even word, hence in the de ning relation there exists no even word and $a_{2r+1} = 0$ for all r:

Since there are a_{2r} words of size 2r, the total number of letters which appear in words of this size is $2ra_{2r}$: If $a_{2r;j}$ is the number of times in which letter B_j appears in words of size 2r, we have

$$X^{1}$$

 $2r_{j} = 2ra_{2r};$ (17)
 $j=1$

• for all r. therefore and according to (14) and (15), $2r_{12} = 2r_{12} =$

$$Z_{r;l}$$
; lot all r , therefore

$$2r;j = \frac{2r}{1}a_{2r}$$
:

and the number of words of the same size 2r which do not contain the letter $2r_{ij} = (1 \quad 2r = 1)a_{2r}$. B_i is a_{2r}

To obtain the confusion chain corresponding to B_i, we multiply each word of the generating relation by that factor. All the e ects obtained will be odd. The e ects of size 2r + 1 in this chain correspond to either words of size 2r in the de ning relation which do not include factor B_i or words of size 2r + 2 in the de ning relation which do include factor B_j. If $c_{2r+1;j}$ is the number of e ects of size 2r + 1 in the chain, we have

$$c_{2r+1;j} = (a_{2r} \quad 2r;j) + 2r+2;j$$
$$= \frac{1}{1} \frac{2r}{a_{2r}} + \frac{2r+2}{1} a_{2r+2};j$$

All these odd e ects can be found in the confusion chains of the main e ects. The total number of e ects of size 2r + 1 is $P_{j=1}^{l} c_{2r+1;j} = \frac{1}{2r+1}$ and therefore

$$(1 \quad 2r)a_{2r} + (2r+2)a_{2r+2} = \frac{1}{2r+1}$$
:

Solving for a_{2r+2} we obtain the recurrence law. Since the design is of resolution IV, the initial value of the law is $a_2 = 0$:

5 W ord-length pattern

We will show a simple way of obtaining the WLP of a 2^{k} p design with generators (12). For this purpose we shall now introduce the concept of word-length pattern polynom ial (W LPP).

De nition 3 Let d H_m be a 2^k ^p design with W LP, W = $(a_1; a_2; ...; a_k)$: The polynom ial P_d associated to this design is given by

$$P_d(u) = 1 + a_1 u + a_2 u^2 + tuka:$$

W e shall refer to it as the word length pattern polynom ial (W LPP).

The above de nition is valid for the case of full designs where $P_d(u) = 1$.

For simplicity we shall denote by $P_m = P_{O_m}$ the polynom ial associated to O_m , whose one cients a $_{2r}$ can be obtained by applying Theorem 3. Let us call

$$Q_{m}(u) = \sum_{r=1}^{2m} b_{2r} u^{2r}$$
 (18)

the polynom ial with coe cients b_{2r} $b_{2r;j}$ de ned in the preceding section. The equation (16) can be rewritten as

$$P_{m}(u) + (2^{m-1} \quad 1)Q_{m}(u) = \frac{2^{m} \quad 2^{m-1}}{2r} \quad u^{2r}:$$
(19)

W e will refer to $Q_{\,m}\,$ as the e ect-length pattern polynom ial for the even alias chain .

Let d H_m be the 2^{k-p} design de ned as $d = O_m$ [e; where O_m is the design (8) and e E_m with r = k n=2 columns. Consider the design e, a design form ed with columns from E_m : The set E_m is isomorphic to H_m 1; therefore any design e has a maximum of m 1 independent columns and is isomorphic to a design of H_m 1. The word length pattern of e can be obtained taking into account the de nition of word given in (2) or, alternatively, it could be nd the isomorphic set of H_m 1 and write it as in (4). For example, the design with generators (9) contains both O_4 and the subset

of

$$E_4 = fAB; AC; AD; BC; BD; CD; ABCDg:$$

 E_4 is formed by all the possible even combinations of the basic columns A;B;C;D. It can be seen that the rank of E_4 is 3. Using the additional factors in (9) to de ne the generators J = AD; K = BD; L = CD and M = ABCD; the set e is isomorphic to fJ;K;L;JK Lg; which de nes a 2^{4-1} design of H₃. The de ning relation of e is I = JK LM and hence its W LPP is $P_e(u) = 1 + u^4$:

Theorem 4 Let d be a 2^{k} ^p design de ned by d = O_m [e; where O_m H_m is the saturated design of resolution IV and e E_m . The (W LPP) of d is given by

$$P_{d}(u) = (1 + u)^{r}Q_{m}(u) + P_{e}(u) P_{m}(u) Q_{m}(u)]; \qquad (20)$$

where r = k n=2; P_m and P_e are the W LPP of O_m and e; respectively, and

$$Q_{m}(u) = \frac{1}{2^{m-1}} \frac{4^{2^{m-2}}}{4^{m-1}} \frac{2^{m-1}}{2^{m-1}} u^{2i} P_{m}(u)^{5}:$$

Proof. Suppose that the design d has only one more column than O_m : In this case, the generators of d are the q = n=2 m generators of O_m given in (8), plus $B_{m+q+1} \stackrel{0}{_1}$; where $\stackrel{0}{_1}$ has an even number of basic factors. The dening relation has 2^{q+1} words, the rst 2^q correspond to the design O_m which has W LP polynom ial P_m . The remaining 2^q words are the result of multiplying the 2^q words of the dening relation of O_m by $B_{m+q+1} \stackrel{0}{_1}$: W hen multiplying the dening relation of O_m by $B_{m+q+1} \stackrel{0}{_1}$: W hen multiplying the dening relation of O_m by $B_{m+q+1} \stackrel{0}{_1}$ we obtain the alias chain associated to $\stackrel{0}{_1}$ plus the new letter B_{m+q+1} in each e ect. The e ects of size 2i in the alias chain of $\stackrel{0}{_1}$ become words of size 2i+1 in the dening relation of $\stackrel{0}{_1}$ is Q_m (u); it will be uQ_m (u) for the chain $B_{m+q+1} \stackrel{0}{_1}$ so that

$$P_{d}(u) = P_{m}(u) + uQ_{m}(u)$$
:

A ssume now that d is given by O_m plus two additional columns, i.e., we add $B_{m+q+1} \stackrel{0}{_{1}}$ and $B_{m+q+2} \stackrel{0}{_{2}}$ to the generators of O_m : The dening relation of d is formed by the dening relation of O_m plus the words resulting from multiplying the dening relation of O_m by $B_{m+q+1} \stackrel{0}{_{1}}$; $B_{m+q+2} \stackrel{0}{_{2}}$ and those corresponding to the product of both, $B_{m+q+1}B_{m+q+2} \stackrel{0}{_{1}} \stackrel{0}{_{2}}$: The product $\stackrel{0}{_{1}} \stackrel{0}{_{2}}$ is an element of E_m dierent from $\stackrel{0}{_{1}}$ and $\stackrel{0}{_{2}}$: The contributions of each new generator to the generating equation of d will be: uQ_m (u), corresponding to $B_{m+q+1} \stackrel{0}{_{1}}$; the same value uQ_m (u), corresponding to $B_{m+q+1} \stackrel{0}{_{1}}$; the same value uQ_m (u), corresponding to $B_{m+q+1} \stackrel{0}{_{1}}$; the same value uQ_m (u), corresponding to $B_{m+q+2} \stackrel{0}{_{1}} \stackrel{0}{_{2}}$: The term u^2 is due to the fact that all the e ects of the alias chain $\stackrel{0}{_{1}} \stackrel{0}{_{2}} \stackrel{0}{_{2}}$ will now contain the two new letters $B_{m+q+1}B_{m+q+2}$: The W LP polynom ial of d is

$$P_d(u) = P_m(u) + 2uQ_m(u) + u^2Q_m(u)$$

adding and substracting Q_m (u) to the right hand side, we obtain

$$P_d(u) = (1 + u)^2 Q_m(u) + [P_m(u) Q_m(u)]$$
:

The above result is generalized when $d = O_m$ [e; and the elements of $e = {0 \atop 1}^0; {0 \atop 2}^0; :::; {0 \atop r}$ are independent (r m 1): The independence of the elements of e ensures that any product of a subset of them provides a

di erent elem ent of E_m : W ith r generators one can get $i \atop i$ combinations of i of them that will incorporate $i \atop i u^i Q_m$ (u) to the polynom ial P_d (u);

$$P_{d}(u) = P_{m}(u) + \sum_{i=1}^{X^{r}} u^{i}Q_{m}(u)$$
(21)
= $(1 + u)^{r}Q_{m}(u) + [P_{m}(u) Q_{m}(u)]$

W hen the elements of $e = {0 \\ 1}; {0 \\ 2}; :::; {n \\ r}$ are not independent (this is the case where r > m 1), the product of som e subset of them is equal to I instead of som e element of E_m : Thus, if

$$\begin{array}{cccc}
 0 & 0 & 0 \\
 j_1 & j_2 & j_i = I;
 \end{array}$$

the product of the generators $B_{m+q+j_1} \quad \stackrel{0}{j_1}$, $B_{m+q+j_2} \quad \stackrel{0}{j_2}$; ..., $B_{m+q+j_1} \quad \stackrel{0}{j_1}$ is

$$B_{m+q+j_1}B_{m+q+j_2} m B_{q+j_i}$$

and its contribution to $P_d(u)$ is $u^i P_m(u)$ instead of $u^i Q_m(u)$: Let a_i^0 be the number of subsets of i elements of e the product of which is equal to I: The polynom ial $P_d(u)$ is

$$P_{d}(u) = P_{m}(u) + \sum_{i=1}^{X^{r}} u^{i}Q_{m}(u) + \sum_{i=1}^{X^{r}} a_{i}^{0}u^{i}P_{m}(u) Q_{m}(u)]; \quad (22)$$

where the two st terms from (21) correspond to the counting process if the r elements of e are independent, and the term $\prod_{i=1}^{r} a_i^0 u^i \mathbb{P}_m$ (u) Q_m (u)] corrects this value by taking into account the dependencies on e: 0 nce again, adding and substracting Q_m (u) to the right-hand side of (22) and regrouping term s one gets

$$P_{d}(u) = (1 + u)^{r}Q_{m}(u) + (1 + \sum_{i=1}^{X^{r}} a_{i}^{0}u^{i})P_{m}(u) Q_{m}(u)]$$
:

The polynom $ialP_e(u) = (1 + \prod_{i=1}^{P} a_i^0 u^i)$ is by denition the W LPP of design e: This last result is the expression (20) which we wanted to prove.

Example 2. The W LP for the 2^{12} ⁸ m in imum aberration fraction with generators (9) is obtained by applying (20),

$$P_{d}(u) = (1 + u)^{4}Q_{4}(u) + P_{e}(u) [P_{4}(u) Q_{4}(u)]$$

where $P_4(u) = 1 + 14u^4 + u^8$ is the polynom ial corresponding to the fraction (13), and $Q_4(u) = 4u^2 + 8u^4 + 4u^6$ is obtained from (19) and (18). Also,

 $P_e(u) = 1 + u^4$ is the polynom ial of the 2^{4-1} m in imum aberration design (I = JK LM). By substitution in P_d we obtain:

 $P_d(u) = 1 + 16u^3 + 39u^4 + 48u^5 + 48u^6 + 48u^7 + 39u^8 + 16u^9 + u^{12}$:

The coe cients of P $_{\rm d}$ are the elements of the word length pattern (10).

U sing theorem 4, it is easy to prove that the goodness of the design d in term s of its aberration depends entirely on e:

Theorem 5 Let d be a design de ned by $d = O_m$ [e; where O_m H_m is the saturated design of resolution IV and e E_m . The design d is MA if and only if e is isomorphic to an MA design e^0 H_m 1.

Proof. Let $d_1 = H_m$ and $d_2 = H_m$ be two dimensent $2^k = p$ fractions. The design d_1 is of smaller aberration than d_2 if and only if (by denition of W LPP) $P_{d_1}(u) = P_{d_2}(u)$ has a negative coeclient for the term of lowest order. If $d_1 = O_m$ [e_1 and $d_2 = O_m$ [e_2 , then by (20) we have

$$P_{d_1}(u) \quad P_{d_2}(u) = [P_{e_1}(u) \quad P_{e_2}(u)][P_m(u) \quad Q_m(u)]$$

and since P_m (u) Q_m (u) = 1 b_2u^2 + ; if the coe cient of the lowest order term of P_{e_1} (u) P_{e_2} (u) is negative, the corresponding one for P_{d_1} (u) P_{d_2} (u) will also be negative. Therefore, if e_1 is isom orphic to an MA design of H $_m$ 1, d_1 will also be MA, and vice versa.

This theorem is useful to justify that the design d with generators (9) is MA.This follows from the fact that this design is the union of O₄ and e = fAD; BD; CD; ABCDg; and the subset e is isomorphic to fJ; K; L; JK Lg; which represents the 2^{4-1} MA design.

Knowing the 2^{4-1} MA (m = 3) design it is possible to obtain the 2^{12-8} MA (m = 4) design. This design in turn allows the determination of the 2^{28-23} MA (m = 5) design, and so forth. Given the MA design d H_m with k factors, one can immediately obtain the MA design d⁰ H_{m+1} with 2^{m} + k factors.

The d H_m MA design with a number of factors k > n=2; is obtained as d = O_m [e; where O_m is the (8) design and e E_m with r = k n=2 columns. To determ ine e one should obtain the MA with r factors in H_m 1: Let d⁰ H_m 1 be the MA design with r factors de ned from the basic factors $B_1^0; B_2^0; :::; B_m^0$ 1: The set e is de ned as the transform of d⁰ by the isomorphism T from H_m 1 to E_m de ned by T (B_j^0) = $B_j B_m$ for j = 1;2;:::; 1: W hen r > n=4 the method can be applied iteratively.

Example 3. Let us illustrate, for instance, how to obtain the 2^{28} ²³ MA design. This design is included in H₅; and, following theorem 2, its

rst 16 columns correspond to all the odd combinations (O $_5$) of the basic columns A; B; C; D; E. The remaining 12 columns are a subset of the even combinations of the basic ones (E $_5$) isomorphic to the 2^{12} ⁸ MA design included in H $_4$. The 2^{12} ⁸ MA design (verifying 12 > n=2 = 8) should contain the 8 odd combinations of the 4 independent columns plus 4 other combinations of them. We take $e_0 = fAE$; BE; CE; DEg as the independent columns of E $_5$ and build with them the 8 odd combinations,

e₁ = fAE;BE;CE;DE;ABCE;ABDE;ACDE;BCDEg:

The 7 even combinations of e_0 form the set fAB ;AC ;AD ;BC ;BD ;CD ;ABCD g isomorphic to H₃: From it we take

 $e_2 = fAD ; BD ; CD ; ABCDg$

which is isomorphic to the 2^{4-1} MA design of H₃. The 2^{28-23} MA design is d = 0₅ [e_1 [e_2 :

The case 2^{28} ²³ has been chosen to illustrate the proposed method. A simpler way to build the design in this case is to eliminate 3 columns out of the 31 which form H₅: By results of section 2, it su ces to choose 3 minimum rank columns of H₅. In this case, d is missing just the columns d = fAB;AC;BCg to complete H₅, and the rank of d is the minimum possible.

6 Conclusions

The selection of a 2^{k-p} regular fraction in plies choosing k columns among the n = 2^{m} available in a full factorial design with m = k p factors. When k n=2; it can be shown that the minimum aberration design contains n=2 columns obtained as a product of an even subset of mindependent columns. The choice of the other k n=2 columns requires solving the same problem but now in a smaller set, the full factorial design with m 1 factors. A iterative procedure has been derived from this property that allow s building screening designs (k > n=2) of minimum aberration for large k:

The com parison of designs in terms of aberration requires the com putation of word-length patterns. When k and p are large the direct counting process is very cum bersom e. In this article we introduce a simple relationship, based on products of polynom ials, for com puting the word-length pattern for these designs. This relation provides an interesting correspondence between designs of di erent num ber of runs.

7 Appendix: proof of theorem 1.

We choose $d = \begin{bmatrix} n \\ 1; 2; ...; \\ h \end{bmatrix}^{O}$ so that the complementary design d has the minimum number of words of size 3 in its dening relation. In the complete dening relation of H_m; any factor (letter) appears in (n 2)=2 words of size 3, therefore, if we remove h columns, the number of words of size 3 that we eliminate is

$$a(\overline{d}) = (\frac{n-2}{2})h \quad a_3^0(\overline{d}) \quad 2a_3(\overline{d});$$
(23)

where $a_3^0(\vec{d})$ and $a_3(\vec{d})$ are, respectively, the number of these words which contain two and three eliminated factors. Moreover, in the complete generating equation of H_m any combinations of the two factors appear once in words of size 3, thus

$$\frac{h}{2} = a_3^0 (\overline{d}) + 3a_3 (\overline{d}):$$

Substituting in (23) we nd that the number of words of size 3 that have been eliminated is

$$a(\overline{d}) = \frac{h(n + 1)}{2} + a_3(\overline{d})$$
:

and this num berw illbem axim um whenever $a_3(\overline{d})$ is also as large as possible. The term $a_3(\overline{d})$ denotes the num ber of relations or words

We shall now see that if $a_3(\overline{d})$ is maximum, then \overline{d} is generated by the smallest number of independent columns $v_h \ge N$; with $h < 2^{v_h}$ (note that it is not possible to generate h di erent columns using less than v_h independent columns).

Suppose that the number of independent elements of d is $v > v_h$; we shall now see that it is then possible to de ne a new set with h columns which provides a larger number of words of size 3, which contradicts the statement that a_3 (d) is maximum.

Let J_v be the set form ed by 2^v 1 di erent colum ns generated by the v independent colum ns of d. O ut of the v independent colum ns we choose v 1, which we will call 1; 2; ...; v 1. Let J_v 1 J_v be the subset generated by these colum ns and J_v 1 the complem entary set, such that J_v 1 = $J_v n J_v$ 1: W e divide the set d_0 d into two parts,

$$e_0 = d_0 \setminus J_{v 1} = f_{1}; _{2}; ...; _{s}g$$

and

$$f_0 = d_0 \setminus J_{v_1} = f'_1; '_2; :::; '_h_s g:$$

For this proof we have used on purpose the notation $_{i}$; $'_{j}$ for the columns of J_{v} ; J_{v-1} ; respectively, which, without loss of generality, can be considered as even and odd combinations of the basic factors. As will be seen below, this notation helps to understand the following development, if we bear in m ind properties such as that the product of two even combinations is also even and so forth.

The elements of f_0 J_v are obtained as a product of the generators of $J_v_{1}_{1}$; $_2$; \vdots ; $_{v_1}$ and any other term of f_0 ; for example $'_1$; thus

$$'_{t} = '_{1} \$_{t};$$
 con $\$_{t} 2 J_{v}_{1};$ para $t = 2; ...;$ s: (25)

W ith the new notation, the relations (24) can be divided into two classes:

(A):
$$i + k = I; i; j = k = 2e_0$$
 (26)

and

(B):
$$'_{i_{j_k}} = I '_{i_{j_k}} 2 f_0; k 2 e_0:$$
 (27)

(Note that taking into account the even/odd features no other combinations are possible).

We now replace $'_{t} 2 f_{0}$ by ${}^{0}_{t} 2 J_{v 1}$ (${}^{0}_{t} \neq e_{0}$) as follows: we choose two di erent _a; _b 2 e₀ such that ${}^{0}_{1} = {}_{a b} \neq e_{0}$; (since s < 2^{v 1} this choice is always possible). In (25), $'_{1}$ is replaced by ${}^{0}_{1}$ and we obtain the columns ${}^{0}_{t} 2 J_{v 1}$; such that

$$_{t}^{0} = _{1}^{0}$$
\$ t ;t = 2;3; :::;h s:

We de nee₀⁰ = f $_{t}^{0}$: $_{t}^{0}$ = $_{1}^{0}$ \$ $_{t}$ \neq e₀g; and the new sets e₁ = e₀ [e₀⁰ [$_{1}^{0}$ and

$$f_1 = f'_t = '_1 \$_t 2 f_0 : t = 0 \$_t 2 e_0; t = 2;3; ...; h sg:$$

If $\overline{d_1} = e_1$ [f_1 ; we now show that $a_3(\overline{d_1}) = a_3(\overline{d_0})$. Since $e_0 = e_1$; the other words of type (26) initially form ed can still be form ed after the substitution process. For the words of type (27), there are three possible situations:

1. ' i;' j 2 d1, that is ' i;' j have not no been replaced in which case the
word ' i' j k = I is maintained.

- 2. Both $'_{i};'_{j} \ge \overline{d_{1}}$; have been replaced by ${}^{0}_{i} = {}_{1}\$_{i}$ and ${}^{0}_{j} = {}_{1}\$_{j}$; respectively. In this case ${}^{0}_{i}{}^{0}_{j}_{k} = I$ will be a new word. Given that $'_{i'j}{}_{k} = I$; according to (25) $\$_{i}\$_{j}{}_{k} = I$; therefore $({}_{1}\$_{i})({}_{1}\$_{j})_{k} = {}^{0}_{i}{}^{0}_{j}_{k} = I$:
- 3. $'_{i} \ge \overline{d}_{1};'_{j} \ge \overline{d}_{1};'_{i}$ have been replaced by ${}^{0}_{i} = {}_{1}\$_{i};$ but $'_{j}$ has not, because the substitute ${}^{0}_{j}$ already existed, i.e. ${}^{0}_{j} = {}_{1}\$_{j} \ge \overline{d}_{0}:$ U sing the same reasoning as above, since $'_{i}'_{j} = I;$ then ${}^{0}_{i} {}^{0}_{j} = I$ will be a word that did not exist before (given that ${}^{0}_{i}$ is a new element).

In this case it is possible that two di erent words give equal transform s. Suppose that $'_{i};'_{r};'_{s} 2 f_{0};_{u};_{v} 2 e_{0}$, that

$$'_{i'r_{u}} = I \text{ and } '_{i's_{v}} = I;$$
 (28)

and $'_{i} \neq \overline{d_{1}}$ has been replaced by $_{i}^{0} 2 e_{1}$; while $'_{r}$; $'_{s} 2 f_{1}$ could not be replaced. Moreover, it holds that $_{u}^{0} = _{1} \$_{u} = _{v}$ and $_{v}^{0} = _{1} \$_{v} = _{u}$: In this situation, the two last words (28) have the same transforms $_{i}^{0} u_{v} = I$: But in this case the new word $'_{r}'_{s} _{i}^{0} = I$ is created, which did not exist since $_{i}^{0} \neq \overline{d_{0}}$.

A third coincidence could appear, if i = 1 and a = u and b = v: In this case the transform of (28) coincides with $\begin{bmatrix} 0 \\ 1 \\ a \end{bmatrix} = I$; the relation used to de ne $\begin{bmatrix} 0 \\ 1 \end{bmatrix}$:

The substitution process veri es that $a_3(d_0) = a_3(d_1)$: If there is a triple coincidence, as described in point 3 of the analysis above, then $a_3(\overline{d}_0) = a_3(\overline{d}_1)$; if not, $a_3(\overline{d}_0) < a_3(\overline{d}_1)$ (all words have been transformed and additionally $\begin{pmatrix} 0 \\ 1 \\ a_b \end{pmatrix} = I$):

Repeating the process, a nite sequence of sets $\overline{d}_0; \overline{d}_1; \overline{d}_2; ...; \overline{d}_M$ (M h q); is created, which verify

$$a_3 (d_0) a_3 (d_1) = {}_3 (a_{M-1}) < a_3 (d_M)$$
 (29)

where $\overline{d}_M = J_{v-1}$ ($f_M = ?$): Moreover, in the last step, $a_3 (\overline{d}_{M-1}) < a_3 (\overline{d}_M)$ since the situation described in point 3 can not arise, since $f_M = ?$ (all terms of type $'_t$ have been replaced):

The nalset \overline{d}_M obtained has more words than \overline{d} , which contradicts the statem ent that a_3 (\overline{d}) is maximum. Therefore, the theorem is proved.

8 R eferences

Ankenman, B.E. (1999), \Design of Experiments with Two-and Four-Level Factors." Journal of Quality Technology, 31, 363-375.

Bingham, D. and R. R. Sitter (1999), \M in im um -A berration Two-Level Fractional Factorial Split-P lot Designs." Technom etrics, 41, 62-70.

Box, G.E.P. and J.S. Hunter, (1961). $The 2^{k p}$ fractional factorial designs." Technom etrics. 3, 311–351

Box, G.E.P., W.G.Hunter, and J.S.Hunter, (1978). Statistics for Experim enters. W iley, New York.

Chen, H. and A.S. Hedayat, (1996). $\2^{n-1}$ designs with weak minimum aberration." Annals of Statistics. 24 2536-2548.

Chen, J. (1992). $Some results on 2^n k$ fractional factorial designs and search for minimum aberration designs." Annals of Statistics. 20, 2124-2141.

Chen, J., Sun, D X., and W u, C F J. (1993). A catalogue of two-level and three-level fractional factorial designs with sm all runs." Internat. Statist. Rev. 61 131-145.

Chen, J. and C.F.J.Wu, (1991). $Some results on s^{n-k}$ fractional factorial designs with minimum aberration or optimal moments." Annals of Statistics. 19, 1028–1041.

Franklin, M.F. (1984). \Constructing tables of m in imum aberration p^{n-m} designs." Technom etrics. 26 225–232.

Fries, A. and W. G. Hunter (1980). \M in imum aberration 2^k p designs." Technom etrics 22 601–608.

Huang, P., D. Chen, and J.O. Voelkel (1998), \M in im um -A berration Two-Level Split-P lot Designs." Technom etrics, 40, 314-326.

Pu, K. (1989), \Contributions to fractional factorial designs." Ph. D. dissertation, Univ. Illinois, Chicago.

Tang, B. and W u, C. F. J. (1996) \C haracterization of m in im um aberration 2^{n-k} designs in term s of their com plem entary designs." Annals of Statistics. 24 2549-2559.

 $\label{eq:second} T iao, G \ \ensuremath{\mathcal{L}}\ , B isgaard \ \ensuremath{\mathsf{S}}\ , H ill, \ \ensuremath{\mathsf{W}}\ \ensuremath{\mathsf{J}}\ , Pera, \ \ensuremath{\mathsf{D}}\ . and \ \ensuremath{\mathsf{Stigler}}\ , \ \ensuremath{\mathsf{S}}\ M \ . \ (eds.) \ (2000), \ \ensuremath{\backslash\mathsf{Box}}\ on \ \ensuremath{\mathsf{Q}}\ uality \ and \ \ensuremath{\mathsf{D}}\ iscovery." \ \ensuremath{\mathsf{John}}\ \ensuremath{\mathsf{W}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{N}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{N}}\ \ensuremath{\mathsf{N}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{D}}\ \ensuremath{\mathsf{G}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{G}}\ \ensuremath{\mathsf{G}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{D}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{S}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{G}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{D}}\ \ensuremath{\mathsf{M}}\ \ensuremath{\mathsf{M$